74HCS10

Triple 3-input NAND gate with Schmitt-trigger inputs Rev. 1 — 29 July 2025 Product data sheet

1. General description

The 74HCS10 is a triple 3-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

All inputs are Schmitt-trigger inputs, capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- · Schmitt-trigger inputs
- · Low power consumption
 - Typical supply current (I_{CC}) of 100 nA
 - Typical input leakage current (I_I) of ±10 nA
- ±7.8 mA output drive at 6 V
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD7A (2.0 V to 6.0 V)
- · ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 class 3A exceeds 4000 V
 - CDM ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1500 V
- · Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

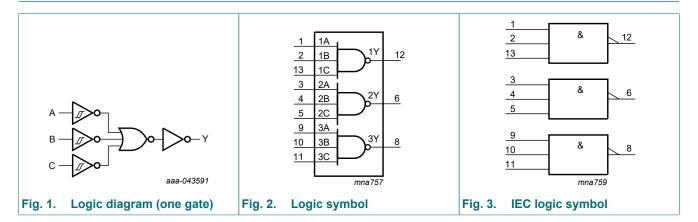
Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74HCS10D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1				
74HCS10PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1				
74HCS10BQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm	SOT762-1				



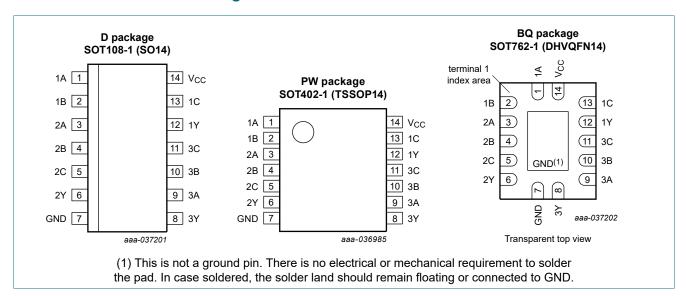
Triple 3-input NAND gate with Schmitt-trigger inputs

4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 9	data input
1B, 2B, 3B	2, 4, 10	data input
GND	7	ground (0 V)
1C, 2C, 3C	13, 5, 11	data input
1Y, 2Y, 3Y	12, 6, 8	data output
V _{CC}	14	supply voltage

Triple 3-input NAND gate with Schmitt-trigger inputs

6. Functional description

Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = don't care

Input	Output		
nA	nB	nC	nY
L	Х	X	Н
X	L	X	Н
X	Х	L	Н
Н	Н	Н	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
Io	output current	V _O = 0 V to V _{CC}		-	±35	mA
I _{CC}	supply current			-	70	mA
I _{GND}	ground current			-70	-	mA
Tj	junction temperature		[2]	-	+150	°C
T _{stg}	storage temperature			-65	+150	°C
V_{ESD}	electrostatic discharge	HBM ANSI/ESDA/JEDEC JS-001 class 3A exceeds 4000 V		-	±4000	V
		CDM ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1500 V		-	±1500	V
P _{tot}	total power dissipation		[3]	-	500	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C

^[2] Guaranteed by design.

^[3] For SOT108-1 (SO14) package: P_{tot} derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P_{tot} derates linearly with 7.3 mW/K above 81 °C. For SOT762-1 (DHVQFN14) package: P_{tot} derates linearly with 9.6 mW/K above 98 °C.

Triple 3-input NAND gate with Schmitt-trigger inputs

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

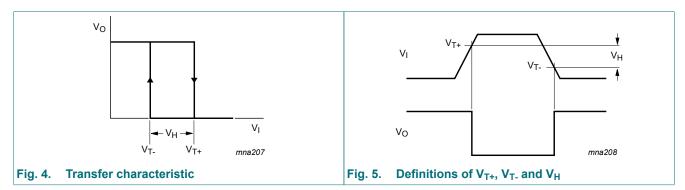
Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{T+}	positive-going	see Fig. 4 and Fig. 5								
	threshold voltage	V _{CC} = 2.0 V	0.7	-	1.5	0.7	1.5	0.7	1.5	٧
vollage	V _{CC} = 4.5 V	1.7	-	3.15	1.7	3.15	1.7	3.15	٧	
		V _{CC} = 6 V	2.1	-	4.2	2.1	4.2	2.1	4.2	٧
		V _{CC} = 3.0 V to 3.6 V	0.4V _{CC}	-	0.7V _{CC}	0.4V _{CC}	0.7V _{CC}	0.4V _{CC}	0.7V _{CC}	٧
		V _{CC} = 4.5 V to 5.5 V	0.38V _{CC}	-	0.7V _{CC}	0.38V _{CC}	0.7V _{CC}	0.38V _{CC}	0.7V _{CC}	٧
V _{T-}	negative-	see Fig. 4 and Fig. 5								
	going threshold	V _{CC} = 2.0 V	0.3	-	1.0	0.3	1.0	0.3	1.0	٧
	voltage	V _{CC} = 4.5 V	0.9	-	2.2	0.9	2.2	0.9	2.2	٧
	_	V _{CC} = 6 V	1.2	-	3.0	1.2	3.0	1.2	3.0	V
		V _{CC} = 3.0 V to 3.6 V	0.2V _{CC}	-	0.5V _{CC}	0.2V _{CC}	0.5V _{CC}	0.2V _{CC}	0.5V _{CC}	V
		V _{CC} = 4.5 V to 5.5 V	0.2V _{CC}	-	0.49V _{CC}	0.2V _{CC}	0.49V _{CC}	0.2V _{CC}	0.49V _{CC}	٧
V _H	hysteresis	see Fig. 4 and Fig. 5								
	voltage[1]	V _{CC} = 2.0 V	0.2	0.52	1.0	0.2	1.0	0.2	1.0	٧
		V _{CC} = 4.5 V	0.4	0.85	1.4	0.4	1.4	0.4	1.4	٧
		V _{CC} = 6 V	0.6	1.1	1.6	0.6	1.6	0.6	1.6	٧
		V _{CC} = 3.0 V to 3.6 V	0.1V _{CC}	0.72	0.38V _{CC}	0.1V _{CC}	0.38V _{CC}	0.1V _{CC}	0.38V _{CC}	٧
	V _{CC} = 4.5 V to 5.5 V	0.09V _{CC}	0.94	0.29V _{CC}	0.09V _{CC}	0.29V _{CC}	0.09V _{CC}	0.29V _{CC}	٧	
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _{OH} = -20 μA; V _{CC} = 2.0 V to 6 V	V _{CC} -0.1	V _{CC} -0.002	-	V _{CC} -0.1	-	V _{CC} -0.1	-	V
		I _{OH} = -4 mA; V _{CC} = 3.0 V	2.7	2.85	-	2.7	-	2.7	-	V
		I _{OH} = -6 mA; V _{CC} = 4.5 V	4.0	4.3	-	4.0	-	4.0	-	V
		I _{OH} = -7.8 mA; V _{CC} = 6.0 V	5.48	5.75	-	5.4	-	5.4	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{OL} = 20 \mu A;$ $V_{CC} = 2.0 \text{ V to 6 V}$	-	0.002	0.1	-	0.1	-	0.1	V
		I _{OL} = 4 mA; V _{CC} = 3.0 V	-	0.14	0.25	-	0.25	-	0.25	V
		I _{OL} = 6 mA; V _{CC} = 4.5 V	-	0.18	0.26	-	0.30	-	0.30	V
		I _{OL} = 7.8 mA; V _{CC} = 6.0 V	-	0.22	0.26	-	0.33	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	±0.01	±0.1	-	±0.25	-	±1.0	μΑ
I _{cc}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	0.1	-	-	0.5	-	2.0	μΑ

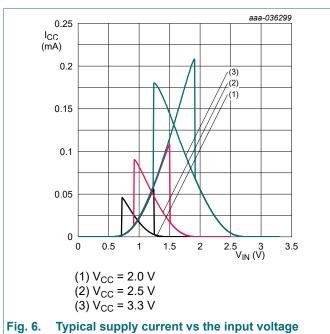
^[1] Guaranteed by design.

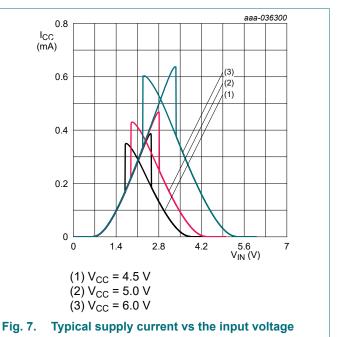
Triple 3-input NAND gate with Schmitt-trigger inputs

9.1. Transfer characteristic waveforms and graphs

9.1.1. For inputs

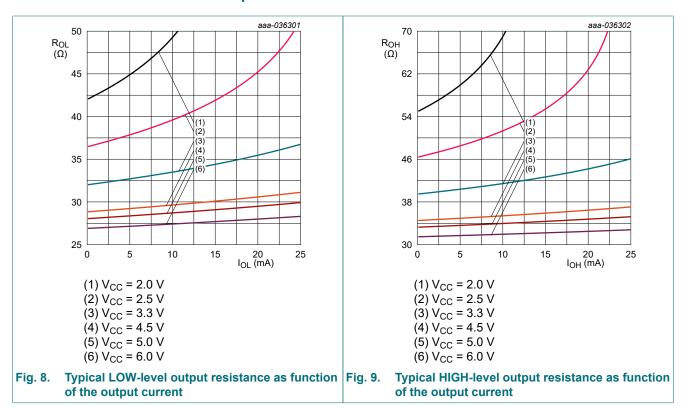






Triple 3-input NAND gate with Schmitt-trigger inputs

9.1.2. For outputs



10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Section 10.1.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t _{pd}	propagation	nA, nB, nC to nY; see Fig. 10 [2]								
	delay	V _{CC} = 2 V	-	14	33	-	37	-	40	ns
		V _{CC} = 4.5 V	-	6	14	-	16	-	17	ns
		V _{CC} = 6 V	-	5	14	-	15	-	16	ns
		V _{CC} = 3.0 V to 3.6 V	-	7	20	-	22	-	24	ns
		V _{CC} = 4.5 V to 5.5 V	-	6	14	-	16	-	17	ns
t _t	transition	nY; see <u>Fig. 10</u> [3]								
	time	V _{CC} = 2 V	-	9	13	-	15	-	16	ns
		V _{CC} = 4.5 V	-	5	7	-	8	-	8	ns
		V _{CC} = 6 V	-	4	6	-	7	-	7	ns
		V _{CC} = 3.0 V to 3.6 V	-	5	8	-	9	-	10	ns
		V _{CC} = 4.5 V to 5.5 V	-	4	7	-	8	-	8	ns
Cı	input capacitance		-	1.5	-	-	5	-	5	pF

Nexperia

Triple 3-input NAND gate with Schmitt-trigger inputs

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _{PD}	dissipation	$f_i = 1 \text{ MHz; } C_L = 0 \text{ pF;}$ [4] $V_I = \text{GND to } V_{CC};$ $V_{CC} = 2.0 \text{ V to } 6.0 \text{ V}$	-	10	-	-	-	-	-	pF

- Typical values are measured at nominal supply voltage.
- [2] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [3] t_t is the same as t_{THL} and t_{TLH}.
 [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs};$

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

10.1. Waveforms and test circuit

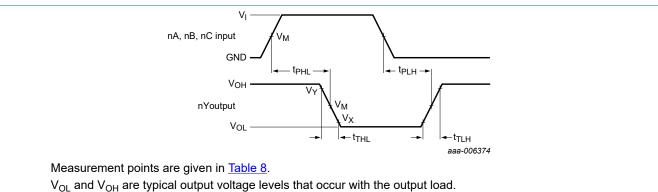
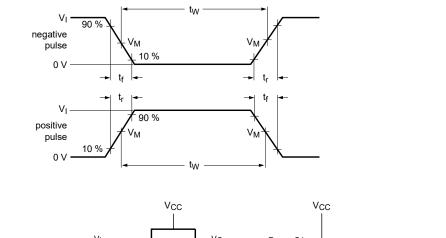


Fig. 10. Propagation delay input (nA) to output (nY)

Table 8. Measurement points

Input	Dutput				
V_{M}	V _M	V _X	V _Y		
0.5V _{CC}	0.5V _{CC}	10 %	90 %		

Triple 3-input NAND gate with Schmitt-trigger inputs



G VI DUT VO RL S1 open

Test data is given in Table 9.

Definitions for test circuit:

 C_L = load capacitance including jig and probe capacitance.

R_L = load resistance.

 R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

S1 = test selection switch.

Fig. 11. Test circuit for measuring switching times

Table 9. Test data

Input		Load		S1 position		
VI	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t_{PZL}, t_{PLZ}
V _{CC}	2.5 ns	50 pF	1 kΩ	open	GND	V _{CC}

Triple 3-input NAND gate with Schmitt-trigger inputs

11. Package outline

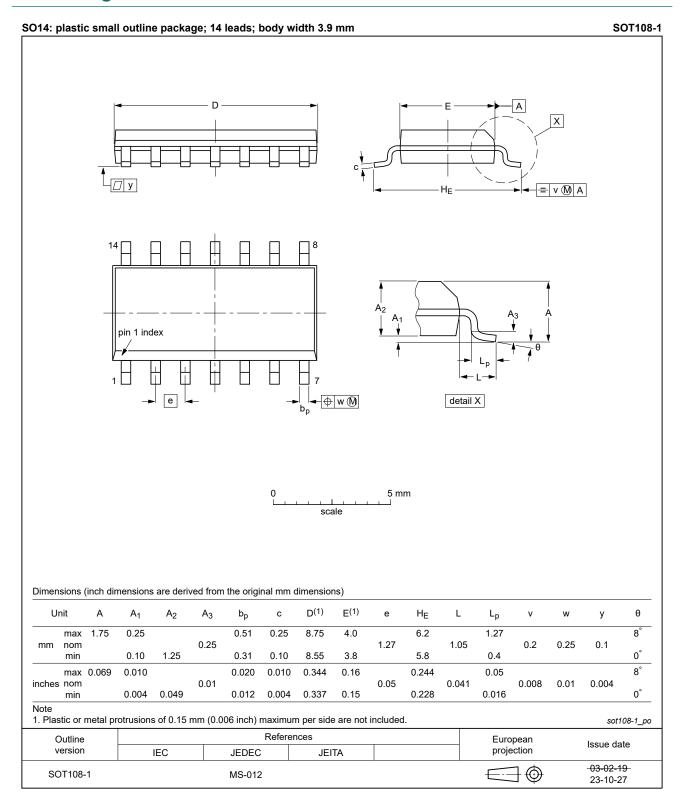


Fig. 12. Package outline SOT108-1 (SO14)

Triple 3-input NAND gate with Schmitt-trigger inputs

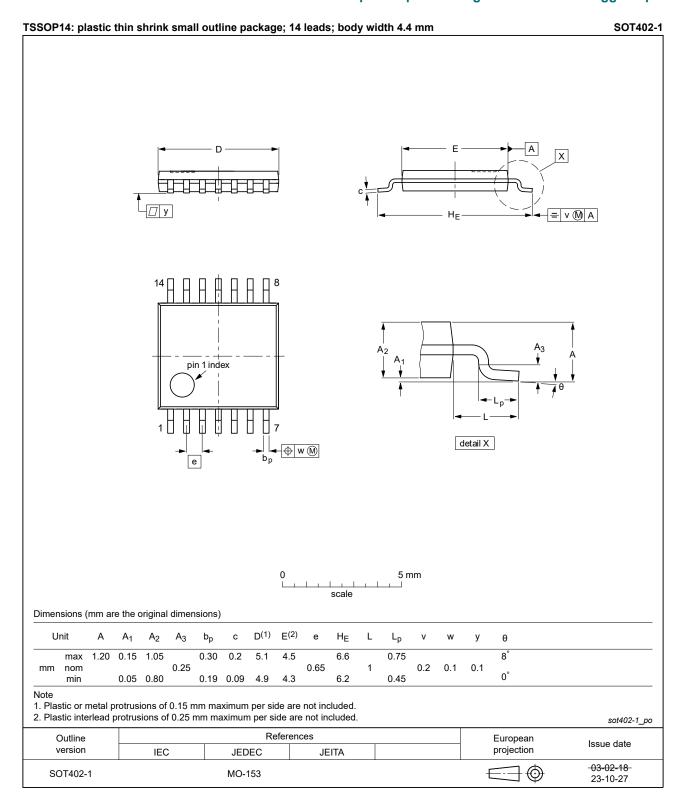


Fig. 13. Package outline SOT402-1 (TSSOP14)

Triple 3-input NAND gate with Schmitt-trigger inputs

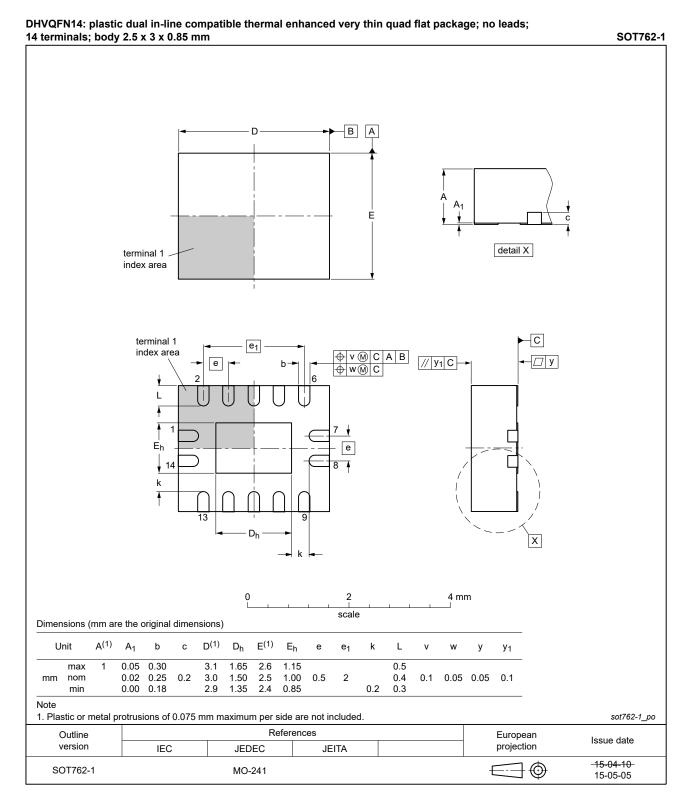


Fig. 14. Package outline SOT762-1 (DHVQFN14)

Triple 3-input NAND gate with Schmitt-trigger inputs

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charge Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HCS10 v.1	20250729	Product data sheet	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

Triple 3-input NAND gate with Schmitt-trigger inputs

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by sustained.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

74HCS10

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2025. All rights reserved

Triple 3-input NAND gate with Schmitt-trigger inputs

Contents

1. General description	<i>'</i>
. Features and benefits	
3. Ordering information	
4. Functional diagram	
5. Pinning information	
5.1. Pinning	
5.2. Pin description	
6. Functional description	
7. Limiting values	
8. Recommended operating conditions	
9. Static characteristics	
9.1. Transfer characteristic waveforms and graphs	
9.1.1. For inputs	
9.1.2. For outputs	
10. Dynamic characteristics	
10.1. Waveforms and test circuit	
11. Package outline	
12. Abbreviations	
13. Revision history	
14. Legal information	
<u> </u>	

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 29 July 2025

[©] Nexperia B.V. 2025. All rights reserved